PCN Num	ber:	2023	31031003.2				N Dat	te:	October 31, 2023		
Title:				• .	ess Tech	nnolo	gy, D	ie Re	evision & datasheet		
	changes for s	elect	devi	ces							
Customer	Contact:		Cha	ange Management	team	De	pt:		Quality Services		
Proposed	1 st Ship Date	1	1 Anr /8 /11/4				ple requests cepted until:		Dec 1, 2023*		
*Sample	requests rece	ved	a fte	r December 1, 20	23 will	not	be su	рро	rted.		
Change Type:											
Assembly Site			☑ Design				☐ Wafer Bump Material				
Assemb	ly Process		□ Data Sheet					Wafer Bump Process			
Assemb	ly Materials		Part number change				M	Wat	Wafer Fab Site		
Mechar	ical Specificati	on	☐ Test Site				\boxtimes	Wat	Wafer Fab Materials		
☐ Packing/Shipping/Labeling				☐ Test Process			\boxtimes	Wafer Fab Process			
				PCN Det	ails						
Description of Change:											
Texas Instruments is pleased to announce the addition of RFAB using the LBC9 qualified process											
technology	technology and Die revision for select devices listed below in the product affected section.										

	C	urrent Fab Site		Additional Fab Site				
Cu	Current Fab Process Site		Wafer Additional Diameter Fab Site		Process	Wafer Diameter		
	SFAB	IMP-C60	150 mm	RFAB	LBC9	300 mm		

The die was also changed as a result of the process change.

As part of these changes, the probe process step will be removed.

The datasheets will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The links to the revised datasheets are available in the table below.



AM26C32, AM26C32C, AM26C32M, AM26C32I

SLLS104M - DECEMBER 1990 - REVISED OCTOBER 2023

(Changes from Revision K (October 2018) to Revision M (October 2023)	Page
٠	Changed Device Information table to the Package Information table	1
٠	Updated the Thermal Information table	5

Product Folder	Current Datasheet Number	New Datasheet Number	Link to full datasheet		
AM26C32	SLLS104L	SLLS104M	http://www.ti.com/product/AM26C32		

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter and 200-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
No Change	No Change		No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City	
SH-BIP-1	SHE	USA	Sherman	
RFAB	RFB	USA	Richardson	

Die Rev:

Current New

Die Rev [2P]	Die Rev [2P]
-	-

Assembly Site Information:

Sample product shipping label (not actual product label)



Product Affected:

AM26C32QDR

For alternate parts with similar or improved performance, please visit the product page on II.com

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

RedBull RS485 Wave 0T4R Part 10/12 (Auto) Approve Date 05-October-2023

Product Attributes

Attributes	Qual Device:	QBS Process, Product Reference:	QBS Package Reference:	
Attilibutes	AM26C32QDR	<u>TLIN2029DQ1</u>	ULQ2003AQDRQ1	
Automotive Grade Level	Grade 1	Grade 1	Grade 1	
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	
Product Function	Interface	Interface	-	
Wafer Fab Supplier	RFAB	RFAB	SH-BIP-1	
Assembly Site	MLA	ASESHAT	MLA	
Package Group	SOIC	-	SOIC	
Package Designator	D	D	D	
Pin Count	16	8	16	

- QBS: Qual By Similarity
- Qual Device AM26C32QDR is qualified at MSL1 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AM26C32QDR	QBS Process, Product Reference: TLIN2029DQ1	QBS Package Reference: ULQ2003AQDRQ1			
Test Group	Test Group A - Accelerated Environment Stress Tests												
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Preconditioning	MSL1 260C	-	1/0/0	-	3/0/0			
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	-	3/231/0			
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22-A118	3	77	Autoclave	121C/15psig	96 Hours	1/77/0	-	3/231/0			
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22-A118	3	77	Autoclave	130C/85%RH	96 Hours	1/77/0	-	3/231/0			
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65/150C	1000 Cycles	-	-	3/210/0			
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65/150C	500 Cycles	-	-	3/231/0			
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	1000 Cycles	-	-	3/210/0			
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	-	-	3/231/0			
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	1/5/0	-	-			
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	1/45/0	-	3/135/0			

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AM26C32QDR	QBS Process, Product Reference: TLIN2029DQ1	QBS Package Reference: ULQ2003AQDRQ1
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	500 Hours	-	-	-
Test Group	B - Acce	lerated Lifetime Simu	ulation Te	ests						
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	1/77/0	-	-
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	140C	480 Hours	-	3/231/0	-
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate	125C	48 Hours	-	3/2400/1 ²	-
Test Group	C - Pack	age Assembly Integr	ity Tests							
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	3/90/0
SD	СЗ	JEDEC J-STD-002	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0
SD	СЗ	JEDEC J-STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions	Cpk>1.67	-	1/10/0	-	-
Test Group	D - Die F	abrication Reliability	Tests							
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AM26C32QDR	QBS Process, Product Reference: TLIN2029DQ1	QBS Package Reference: ULQ2003AQDRQ1
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verification Test	s							
ESD	E2	AEC Q100-002	1	3	ESD HBM	-	2000 Volts	1/3/0	-	-
ESD	E3	AEC Q100-011	1	3	ESD CDM	-	500 Volts	1/3/0	-	-
LU	E4	AEC Q100-004	1	6	Latch-Up	Per AEC Q100- 004	-	1/6/0	-	-
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90/0	-	-
Additional 1	Tests									

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Orderable Part Numbers

The following table contains a list of all TI Orderable Part Numbers (OPNs) released by this qualification per Product Qualification Family definition (AEC Q100 Appendix 1). Group E results shown above cover all part numbers listed here.

AM26C32QDR

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL. ED
- . Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2205-036

[1]-QEM-EVAL-1710-00388. EOS. Discounted [2]-QEM-EVAL-1710-00385. EOS. Discounted

ZVEI IDs: SEM-DE-01, SEM-DE-02, SEM-DE-03, SEM-PW-02, SEM-PW-09, SEM-PW-13, SEM-TF-01

For questions regarding this notice, e-mails can be sent to the Change Management team or your local Field Sales Representative.

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